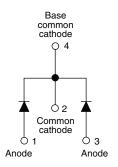


Ultra fast Rectifier, 2 x 3 A FRED Pt®



DPAK (TO-252AA)



PRIMARY CHARACTERISTICS					
I _{F(AV)} 2 x 3 A					
V_{R}	200 V				
V _F at I _F	0.9 V				
t _{rr} typ.	See Recovery table				
T _J max.	175 °C				
Package DPAK (TO-252AA)					
Circuit configuration Common cathode					

FEATURES

- Ultra fast recovery time
- Low forward voltage drop
- Low leakage current
- 175 °C operating junction temperature
- AEC-Q101 qualified
- Meets JESD 201 class 2 whisker test
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





COMPLIANT HALOGEN

DESCRIPTION / APPLICATIONS

Vishay Semiconductors' 200 V series are the state of the art hyper fast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyper fast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Peak repetitive reverse voltage	V_{RRM}		200	V			
Average rectified forward current per device	I _{F(AV)}	Total device, rated V _R , T _C = 159 °C	6				
Non-repetitive peak surge current	I _{FSM}		50	Α			
Peak repetitive forward current per diode	I _{FM}	Rated V _R , square wave, 20 kHz, T _C = 159 °C	6				
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	200	-	-			
		I _F = 3 A	-	0.9	1	V		
Forward voltage	V _F	I _F = 3 A, T _J = 125 °C	-	0.78	0.9			
		I _F = 6 A	-	1	1.2			
		I _F = 6 A, T _J = 125 °C	-	0.89	1.08			
Deverse leekage eurrent	I _R	$V_R = V_R$ rated	-	-	5			
Reverse leakage current		T _J = 125 °C, V _R = V _R rated	-	-	100	<u>μ</u> Α		
Junction capacitance	C _T	V _R = 200 V	-	12	-	pF		
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH		



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST	TEST CONDITIONS			MAX.	UNITS		
		$I_F = 1.0 A, dI_F$	$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		20	35			
Reverse recovery time	t _{rr}	T _J = 25 °C	I _F = 3 A V _R = 160 V dI _F /dt = 200 A/μs	ı	19	ı	ns		
		T _J = 125 °C		-	26	-			
Peak recovery current	I _{RRM}	T _J = 25 °C		-	3.1	-	А		
		T _J = 125 °C		-	4.6	-			
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	30	-	nC		
		T _J = 125 °C		-	60	-			

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}	-65	-	175	°C		
Thermal resistance, junction to case per leg	R _{thJC}	-	-	5	°C/W		
\A/-: -		-	0.3	-	g		
Weight		-	0.01	-	OZ.		
Mounting torque		6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)		
Marking device		Case style DPA	AK (TO-252AA)	6CWH	02FNH		

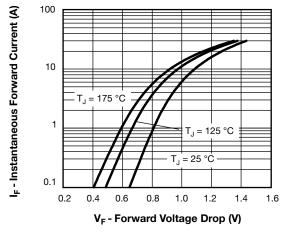


Fig. 1 - Maximum Forward Voltage Drop Characteristics

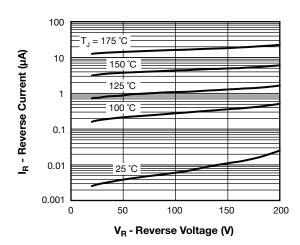


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

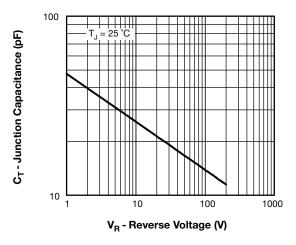


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

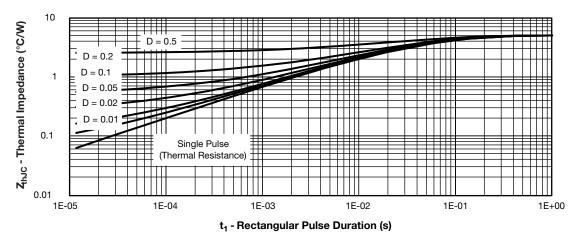


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

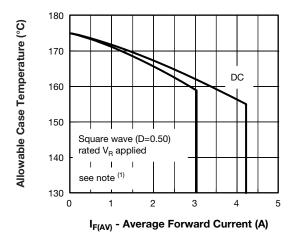


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

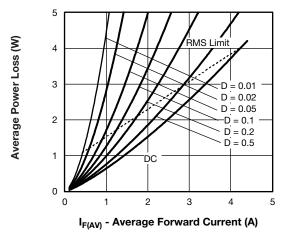


Fig. 6 - Forward Power Loss Characteristics

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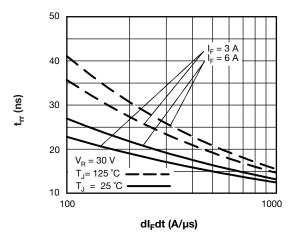


Fig. 7 - Typical Reverse Recovery vs. dl_F/dt

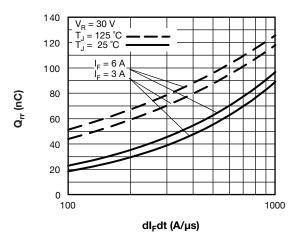


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{rated } V_R \\ \end{array}$

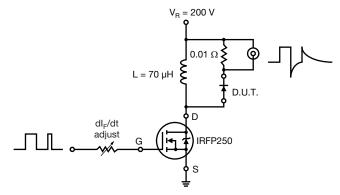
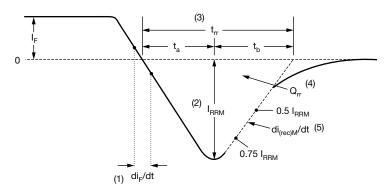


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) di_F/dt rate of change of current through zero crossing
- (2) \mathbf{I}_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_{F} to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

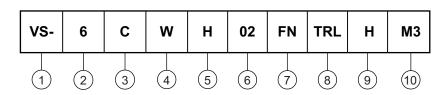
(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (6 = 6 A)

Center tap configuration

Package identifier:

W = DPAK

5 - H = hyperfast recovery

6 - Voltage rating (02 = 200 V)

7 - FN = TO-252AA

- • None = tube (50 pieces)

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

9 - H = AEC-Q101 qualified

10 - Environmental digit:

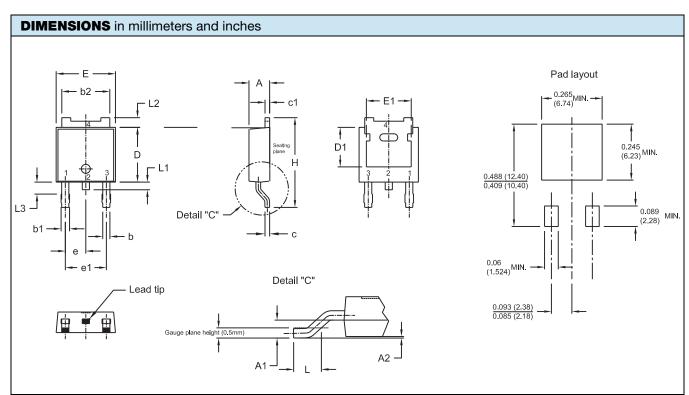
M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-6CWH02FNHM3	75	3000	Antistatic plastic tube				
VS-6CWH02FNTRHM3	2000	2000	13" diameter reel				
VS-6CWH02FNTRRHM3	3000	3000	13" diameter reel				
VS-6CWH02FNTRLHM3	3000	3000	13" diameter reel				

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95519</u>				
Part marking information	www.vishay.com/doc?95518			
Packaging information	www.vishay.com/doc?95033			



D-PAK (TO-252AA)



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.21	2.38	0.087	0.094	
A2	0.03	0.127	0.001	0.005	
b	0.71	0.88	0.028	0.035	
b1	0.76	1.14	0.030	0.045	
b2	5.23	5.44	0.206	0.214	
С	0.46	0.58	0.018	0.023	
C1	0.46	0.58	0.018	0.023	
D	5.97	6.22	0.235	0.2455	
D1	4.32	4.45	0.170	0.175	
Е	6.48	6.73	0.255	0.2655	
E1	4.49	5.50	0.177	0.217	

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
A1	0.89	1.14	0.035	0.045	
Н	9.65	10.41	0.380	0.410	
L	1.40	1.78	0.055	0.070	
е	2.28 BSC		0.09 BSC		
e1	4.57 BSC		0.18 BSC		
L1	0.64	1.02	0.025	0.040	
L2	0.89	1.27	0.035	0.050	
L3	1.15	1.52	0.040	0.060	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L3 only for reference
- Dimension D1, E1, L2 and b2 establish a minimum mounting surface for thermal pad
- (4) Dimensions D and E do not include mold flash.
- (5) Outline conforms to JEDEC outline TO-252AA



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